

CSM200LAP Hall-effect Current Sensor

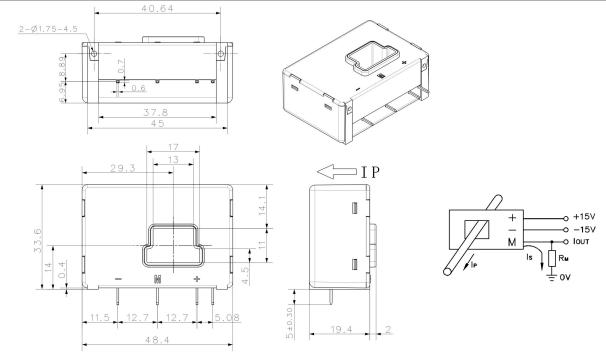


Closed loop current sensor is based on the principle of Hall-effect. It can be used for measuring AC,DC,pulsed and mixed current.

| Electr | rical characteristics | | |
|------------------|--|---|------------|
| | Type | CSM200LAP | |
| I _{PN} | Primary nominal input current | 200 | A |
| lρ | Measuring range of primary current | 0~±300 | A |
| l _{OUT} | Secondary nominal output current | 100 | mA |
| K _N | Conversion ratio | 1:2000 | |
| R _M | Measuring resistance | V _C =±12V/I _{PN} 0-28 | Ω |
| | | V _C =±12V/I _P 0-5 | Ω |
| | | V _C =±15V/I _{PN} 0-58 | Ω |
| | | V _C =±15V/I _P 0-9 | Ω |
| Vc | Supply voltage | ±12~±15(±5%) | V |
| Ic | Current consumption | V _C =±15V 15+Is | mA |
| V_{D} | Insulation voltage | AC/50Hz/1min 3 | kV |
| ٤L | Linearity | <0.15 | %FS |
| Х | Accuracy | T _A =25°C <±0.5 | % |
| lo | Zero offset current | T _A =25℃ <±0.2 | mA |
| I _{OM} | Residual current | I _P →0 <±0.15 | mA |
| Іот | Thermal drift of I ₀ | I _P =0 T _A =-40~+85°C ≤±0.005 | mA/℃ |
| di/dt | di/dt accurately followed | >200 | A/µs |
| T _R | Response time | I _P =I _{PN} 10%-90% <1 | μs |
| f | Frequency bandwidth(-1dB) | DC~100 | kHz |
| TA | Ambient operating temperature | -40~+85 | $^{\circ}$ |
| Ts | Ambient storage temperature | -40~+100 | °C |
| Rs | Secondary coil resistance(T _A =85℃) | 81 | Ω |
| m | Mass | 40 | g |
| | Standard | Q/320115QHKJ01-2016 | |

Dimensions of drawing (mm)

Connection



Remarks

- ·Incorrect connection may lead to the damage of the sensor. I_{SN} is positive when the I_P flows in the direction of the arrow.
- ·Dynamic performance (di/dt and response time) are best with a primary bar in the center of the through-hole.